

Studying the Effect of Oxygen on the Geometrical, Electronical and Thermodynamics Properties of SnO₂ Pyramid using Density Functional Theory

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Abstract

Light atoms, such as oxygen, are treated with the 6-311G** basis sets, and heavy atoms, like tin (Sn), are treated with SDD (Stuttgart/Dresden) basis sets. A density functional theory (DFT) with a B3LYP hybrid functional calculation needs to be done to work out the geometrical and electronic properties, such as the highest occupied molecular orbital (HOMO), the lowest unoccupied molecular orbital (LUMO), and the energy gap, as well as the thermodynamic properties, such as Gibbs free energy, enthalpy, entropy, and heat capacity of the tin dioxide (SnO₂) pyramid nanocluster structure as a function of the number of oxygen atoms. These theoretical calculations were performed using Gaussian 09W, while the geometry was visualized using Gaussian View 05. It was found that the SnO₂ pyramid nanocluster energy gap in the beginning increased with the increase of the oxygen atoms and reached a maximum at Sn₁₀O₁₆, then dropped to a minimum value at 2.55 eV for Sn₁₀O₁₇. The Gibbs free energy and enthalpy values became more negative, indicating that the reaction was exergonic.

Article Info.

Keywords:

Tin Dioxide, Electronic Properties, Density of State, Gaussian 09W, Density Functional Theory (DFT).

Article history:

Received: Feb. 09, 2025

Revised: May, 06, 2025

Accepted: May, 13, 2026

Published: Jun. 01, 2026

1. Introduction

The n-type semiconductor tin dioxide (SnO₂) has a bandgap of 3.4-3.6 eV. It is not only highly transparent and chemically stable but also mechanically stable, which makes it preferable for dye-sensitized solar cells, various gas sensors, the industry of optoelectronics, electrochromic devices, and electrodes. Although SnO₂ has been a favourite option among gas sensors due to its high charge carriers' mobility and their reliable chemical and thermal resistance, this material has hardly been used as a chemical sensor for heavy metal ions in an aqueous condition [1-7]. A broad spectrum of oxides has characteristics of electrical properties that change under the effect of oxidizing and reducing gases, and have gained widespread sensitivity against oxidizing and reducing gases. Of those, SnO₂ has been, for many years, the most promising and also the most widely used in practical applications. SnO₂ stands out by having two main properties: high gas-type sensitivity and low cost. Many doping materials can be utilized for SnO₂ gas sensors to get faster response time, lower operation temperature, and be more selective [8-14].

In a previous study, Jafer and Hussein investigated SnO₂ as a nitrogen gas sensor. Using density functional theory (DFT), which is a method that uses an electron density to calculate the physical properties and compare with experimental results, the B₃LYP level, with 6-311G** basis sets for light atoms like nitrogen and oxygen, and SDD basis sets for heavy atoms like tin. The transition state of the SnO₂ nanocluster with NO₂ gas molecules was determined. These simulations were conducted via Gaussian 09W across a temperature range of 273 to 373 K, yielding the activation and reaction values for Gibbs free energy, enthalpy, and entropy [15].

Additionally, DFT has been utilized to p-n heterojunction of SnO₂ nanoparticles/reduced graphene oxide as a sensor for NO₂ gas. This work demonstrated that gas interaction with the SnO₂ surface is energetically more favourable than rGO edges due to lower Gibbs free energy, aligning well with existing literature [16,17]. While our previous work focused on establishing a theoretical foundation for these materials in various applications, such as a sensor or photo detector. In the present work, SiO₂ with a varying oxygen atom content was used as a humidity sensor.



2. Methodology

The structure and various properties of the sensing materials were analysed using the B₃LYP (Becke three-parameter, Lee-Yang-Parr) level of DFT. The 6-311G** basis set was applied for lighter atoms like oxygen, while the Stuttgart/Dresden (SDD) basis set was used for heavier atoms like tin. The Gaussian 09W molecular software was employed during the calculations, along with the Gaussian View 05, which was used as a supplementary tool to look at the geometric structure [18 -25], as presented in Fig. 1.

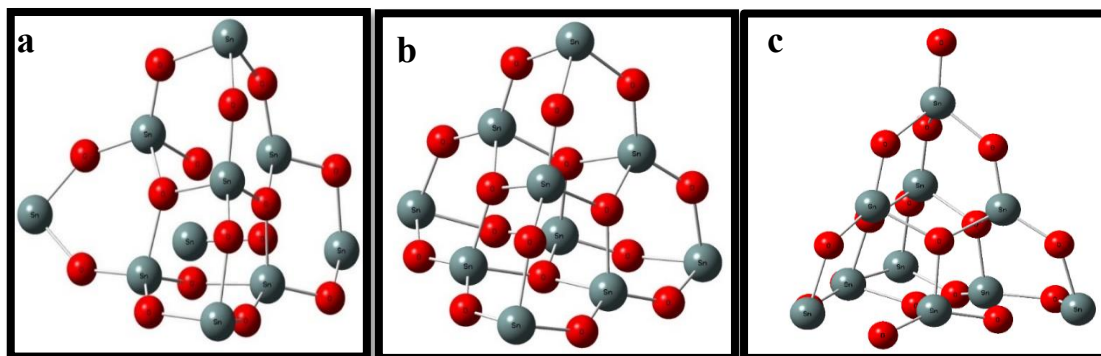


Figure 1: Geometrical optimization of (a) Sn₁₀O₁₅, (b) Sn₁₀O₁₆ and (c) Sn₁₀O₁₇.

3. Results and Discussion

3.1. Electronics Properties

The energy gap difference between the levels of the Highest Occupied Molecular Orbital (HOMO) and the Lowest Unoccupied Molecular Orbital (LUMO) was determined through Eq. (1):

$$E_g = |\text{LUMO} - \text{HOMO}| \quad (1)$$

Fig. 2 demonstrates the energy levels of the HOMO and the LUMO for (a) Sn₁₀O₁₅, (b) Sn₁₀O₁₆, and (c) Sn₁₀O₁₇ with the variation of the number of oxygen atoms (O).

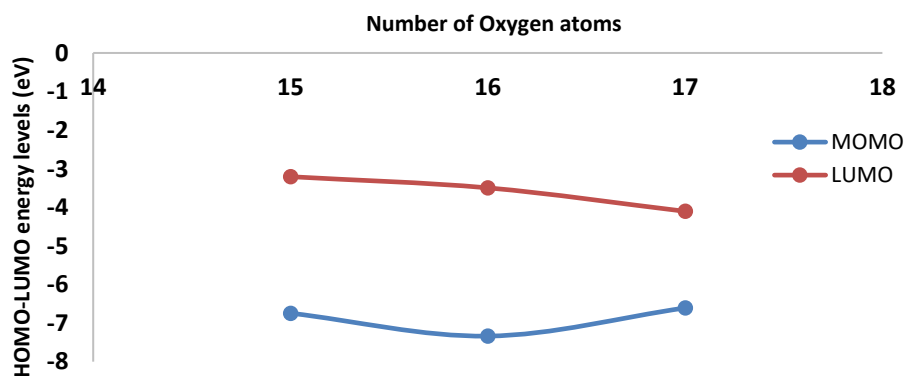


Figure 2: Energy levels HOMO and LUMO of Tin dioxide as a function of different number of oxygen atoms.

Fig. 3 shows the density of state of (a) Sn₁₀O₁₅, (b) Sn₁₀O₁₆, and (c) Sn₁₀O₁₇ as a function of the energy levels. The energy gap between the HOMO was calculated from Eq. (1) to be 3.566, 3.841, and 2.505 eV, respectively.

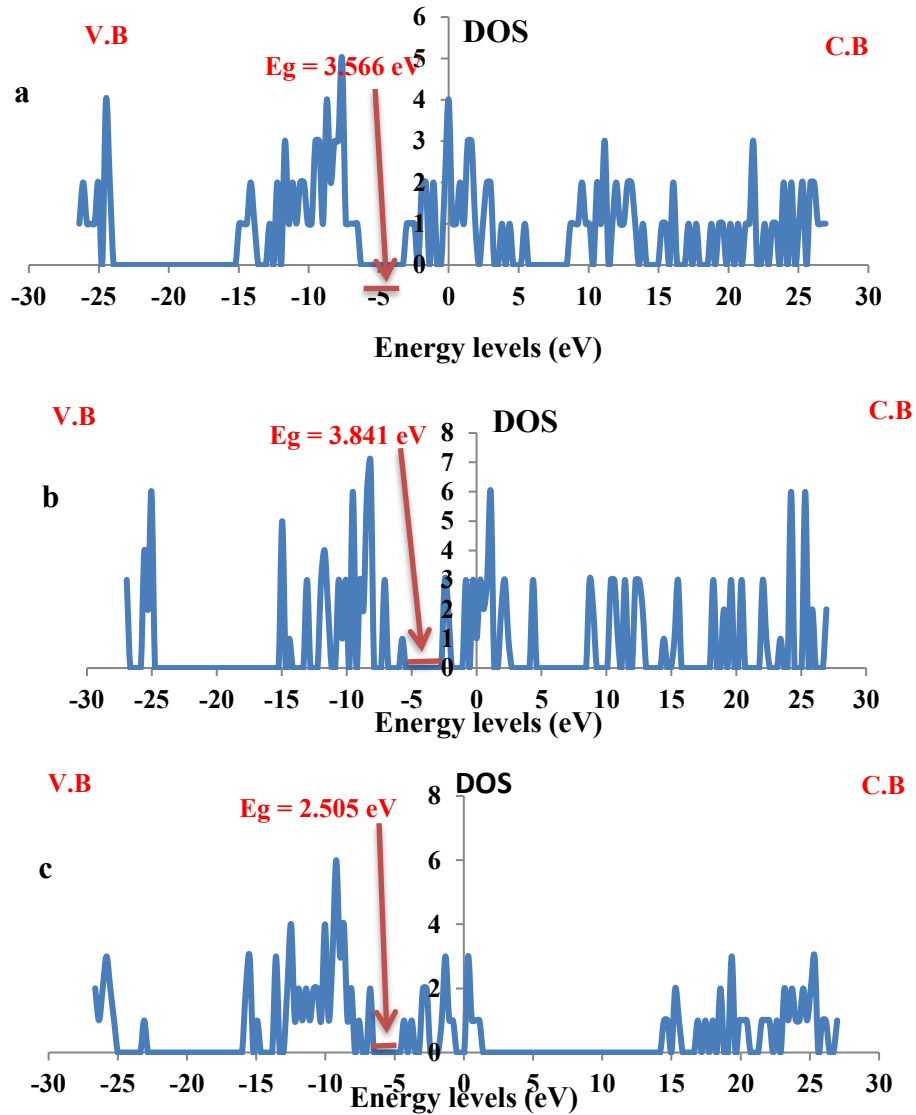


Figure 3: Density of states for (a) $Sn_{10}O_{15}$, (b) $Sn_{10}O_{16}$ (c) $Sn_{10}O_{17}$.

Fig. 4 shows the relation between the calculated energy gap, taken as 3.6, 3.8 and 2.5 eV for tin dioxide and the number of oxygen atoms.

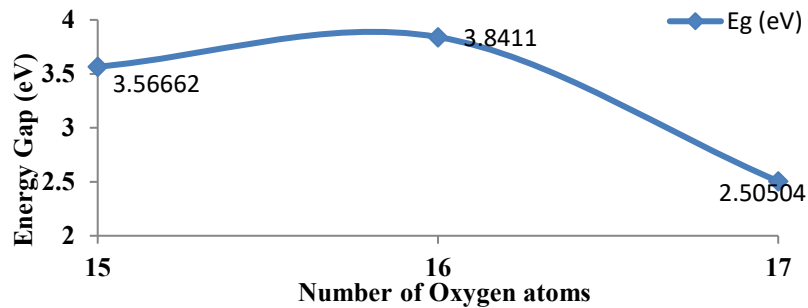


Figure 4: Energy gap for (a) $Sn_{10}O_{15}$, (b) $Sn_{10}O_{16}$ (c) $Sn_{10}O_{17}$ as a function of the number of oxygen atoms.

3.2. Thermodynamic Properties

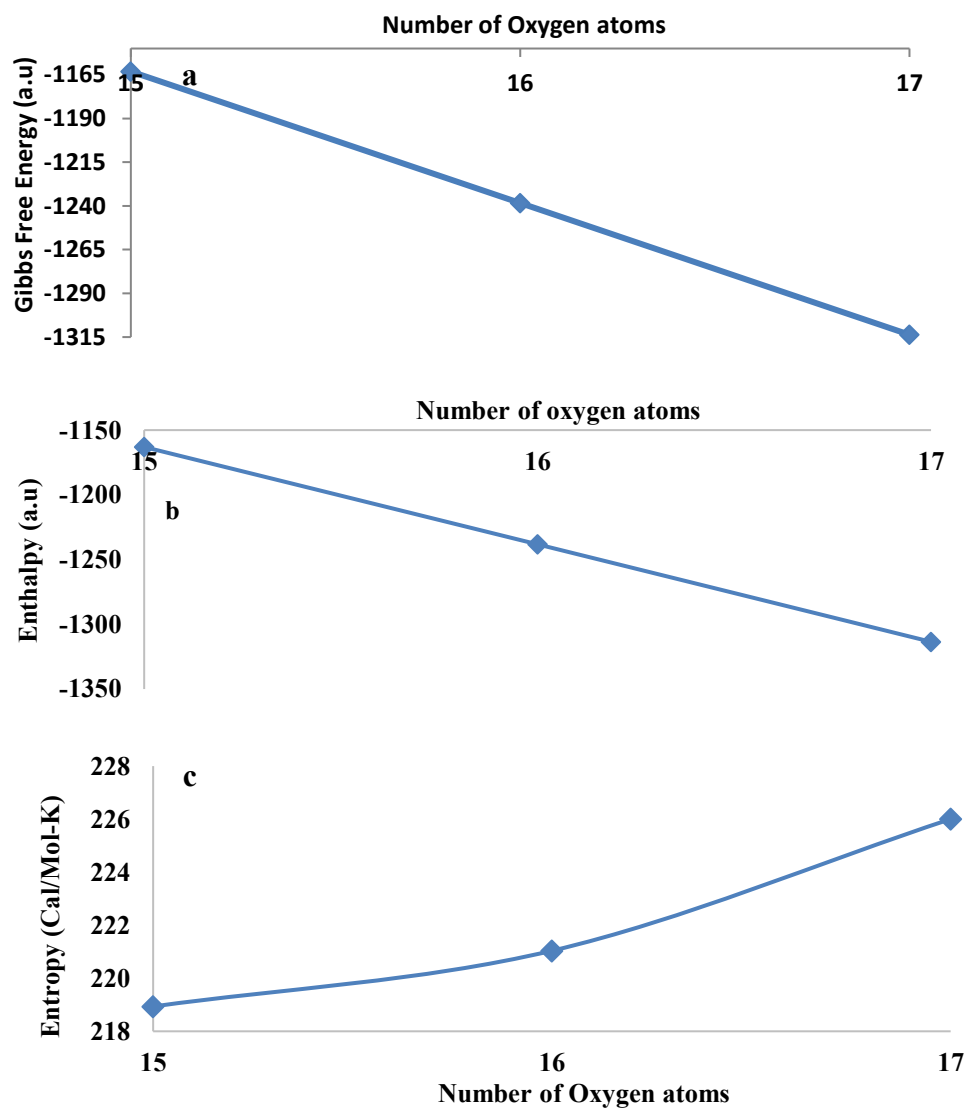
Fig. 5a and b show Gibbs free energy and Enthalpy as a function of the number of oxygen atoms. It was found that the values increased (in negative sign), which indicates that the reaction is exergonic, according to Eq. (2) [26-28].

$$\Delta G = \Delta H - \Delta ST \quad (2)$$

Fig. 5 (c, d) shows the entropy and specific heat capacity as a function of the number of oxygen atoms. It was found that the values increased according to Eqs. (2 and 3):

$$C = \frac{Q}{m \cdot \Delta T} \quad (3)$$

where C is the specific heat capacity, Q is the amount of heat, m is the mass of the sample, and ΔT is the temperature difference.



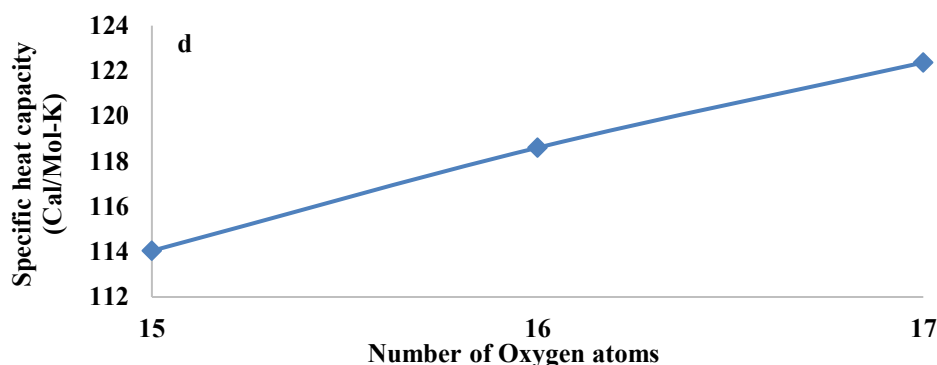


Figure 5: Thermodynamic properties for (a) $\text{Sn}_{10}\text{O}_{15}$, (b) $\text{Sn}_{10}\text{O}_{16}$ (c) $\text{Sn}_{10}\text{O}_{17}$ as a function of the number of oxygen atoms.

4. Conclusions

DFT with B₃LYP hybrid functional was used to calculate the electronic and thermodynamic properties of tin oxide as a function of the number of oxygen atoms. The tin oxide pyramid nanocluster interacting with oxygen was explained in terms of geometry. The magnitude of the energy gap was concluded from the molecular orbital HOMO and LUMO to obtain the response value of oxygen as a gas sensor. The Gibbs free energy and enthalpies were negative, meaning the reactions were exergonic. The fact that both the entropy and heat capacity values were positive indicates that the structure was unstable thermodynamically.

Conflict of interest

The authors declare that they have no conflict of interest.

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دراسة تأثير الاوكسجين على الخواص التركيبية والالكترونية والحرارية لأكسيد القصدير الهرمي باستخدام نظرية دالية الكثافة

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الخلاصة

تمت معالجة الذرات الخفيفة مثل الاوكسجين بمجموعات الأساس 6-311G** وتم التعامل مع الذرات الثقيلة مثل القصدير (Sn) بمجموعات أساس SDD (شتوتغارت/دريسدن) من خلال استخدام نظرية دالية الكثافة (DFT) مع الدالة الهجينة B3LYP لتحديد الخصائص الهندسية والإلكترونية، مثل أعلى مدار جزيئي مشغول (HOMO)، وأدنى مدار جزيئي غير مشغول (LUMO)، وفجوة الطاقة بالإضافة إلى الخصائص الديناميكية الحرارية مثل طاقة جيبس الحرة والانتالبي والإنتروبي والسعة الحرارية للتركيب النانوي الهرمي لثاني أكسيد القصدير SnO₂ كدالة لعدد ذرات الاوكسجين. تم إجراء هذه الحسابات النظرية باستخدام Gaussian 09W في حين تم الحصول على الشكل الهندسي الفراغي بواسطة Gaussian View 05. وقد وجد أن فجوة الطاقة SnO₂ زادت في البداية مع إضافة ذرات الاوكسجين ووصلت إلى الحد الأقصى عند Sn₁₀O₁₆ ثم انخفضت إلى القيمة الأدنى 2.50 إلكترون فولت عند Sn₁₀O₁₇. بينما أصبحت طاقة جيبس الحرة وقيم الانتالبي أكثر سلبية، وهذا يعني أن التفاعل لا يزال باعنا للطاقة.

الكلمات المفتاحية: ثنائي اوكسيد القصدير، الخواص الالكترونية، كثافة الحالات، برنامج Gaussian 09W، نظرية دالية الكثافة.